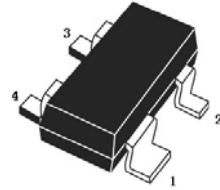


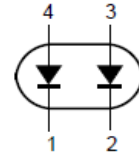
## Features

- High switching speed.
- Continuous reverse voltage.
- Repetitive peak reverse voltage.
- Repetitive peak forward current.



## Applications

- High speed switching in e.g. surface mounted circuits.



## Ordering Information

Type No.	Marking	Package Code
BAS56	L51	SOT-143

### MAXIMUM RATING @ Ta=25°C unless otherwise specified

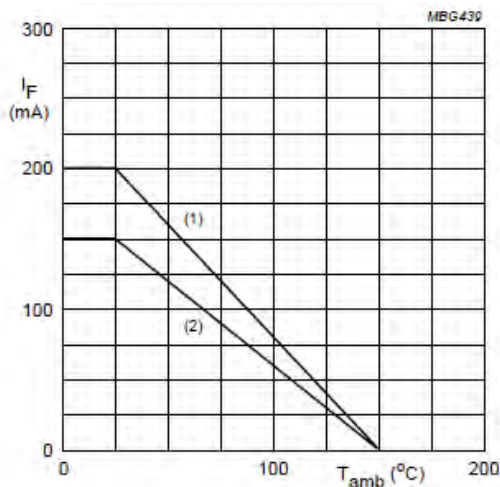
Characteristic	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	60	V
Repetitive Peak Reverse Voltage series connection	$V_{RRM}$	120	V
Continuous Reverse Voltage	$V_R$	60	V
Continuous Reverse Voltage series connection	$V_R$	120	V
Continuous Forward Current Single diode loaded(Note1) Double diode loaded(Note1)	$I_F$	200 150	mA
Repetitive peak forward current Single diode loaded Double diode loaded	$I_{FSM}$	600 430	mA
Non-repetitive peak forward current Square wave, $T_j=25^\circ\text{C}$ prior to surge t=1us t=100us t=10ms	$I_{FSM}$	9 3 1.7	A
Total Power Dissipation	$P_d$	250	mW
Storage and Junction Temperature Range	$T_{STG} T_j$	-65 to +150	°C

Note:1.Device mounted on an FR4 printed-circuit board.

### ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	MAX	UNIT	Test Condition
Reverse Leakage Current	$I_R$	-	100	nA	$V_R=60\text{V}$
			100	$\mu\text{A}$	$V_R=60\text{V}, T_j=150^\circ\text{C}$
			100	nA	$V_R=120\text{V}$
			100	$\mu\text{A}$	$V_R=120\text{V}, T_j=150^\circ\text{C}$
Forward voltage	$V_F$	-	1	V	$I_F=200\text{mA}$
Diode Capacitance	$C_D$	-	2.5	pF	$V_R=0\text{V}, f=1.0\text{MHz}$
Reverse Recovery Time	$t_{rr}$	-	6	ns	$I_F=I_R=400\text{mA}$ , $R_L=100\Omega$ $I_{rr}=0.1 \cdot I_R$
Forward recovery voltage	$V_{fr}$	-	2.0		$I_F=400\text{mA}, t_r=30\text{ns}$
			1.5		$I_F=400\text{mA}, t_r=100\text{ns}$

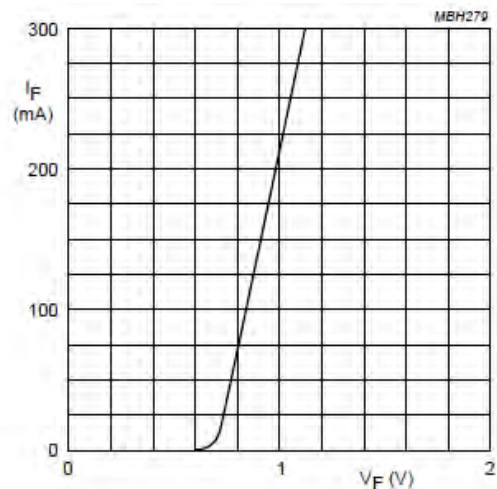
### TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified



Device mounted on a FR4 printed-circuit board.

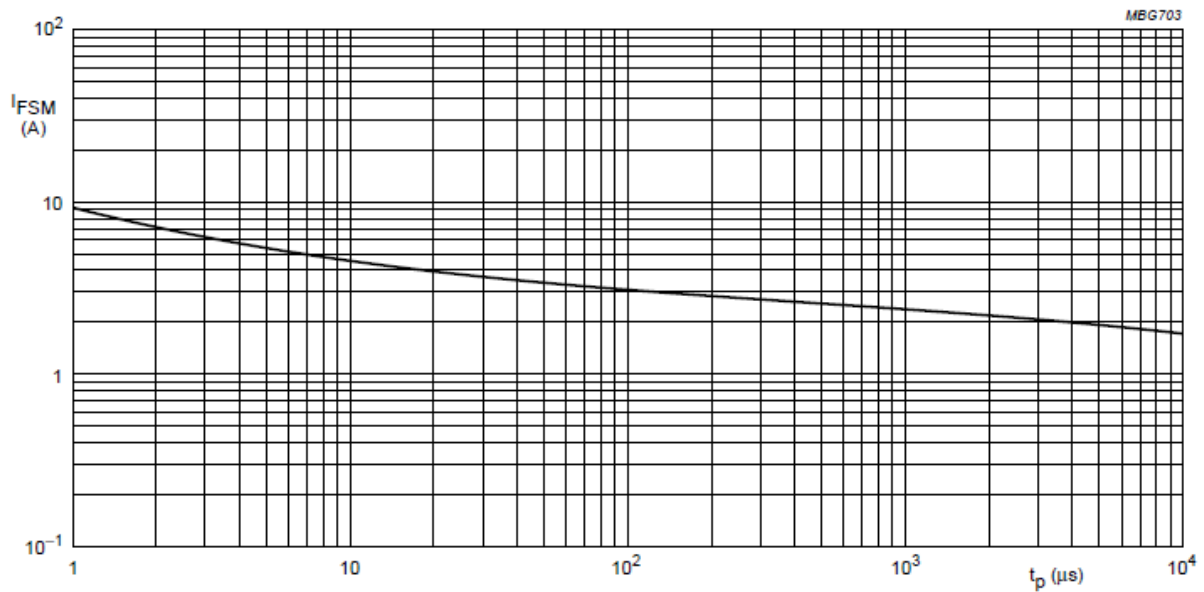
- (1) Single diode loaded.
- (2) Double diode loaded.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



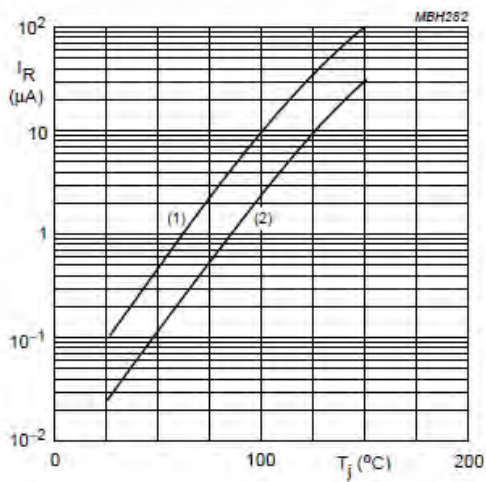
$T_j = 25^\circ\text{C}$ .

Fig.3 Forward current as a function of forward voltage; typical values.



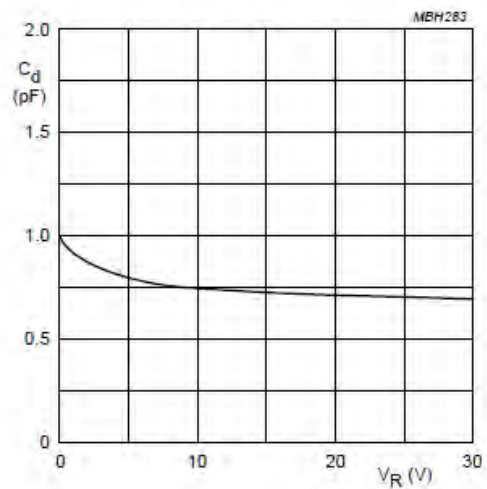
Based on square wave currents.  
 $T_j = 25\text{ }^\circ\text{C}$  prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.



(1)  $V_R = 60\text{ V}$ ; maximum values.  
 (2)  $V_R = 60\text{ V}$ ; typical values.

Fig.5 Reverse current as a function of junction temperature.



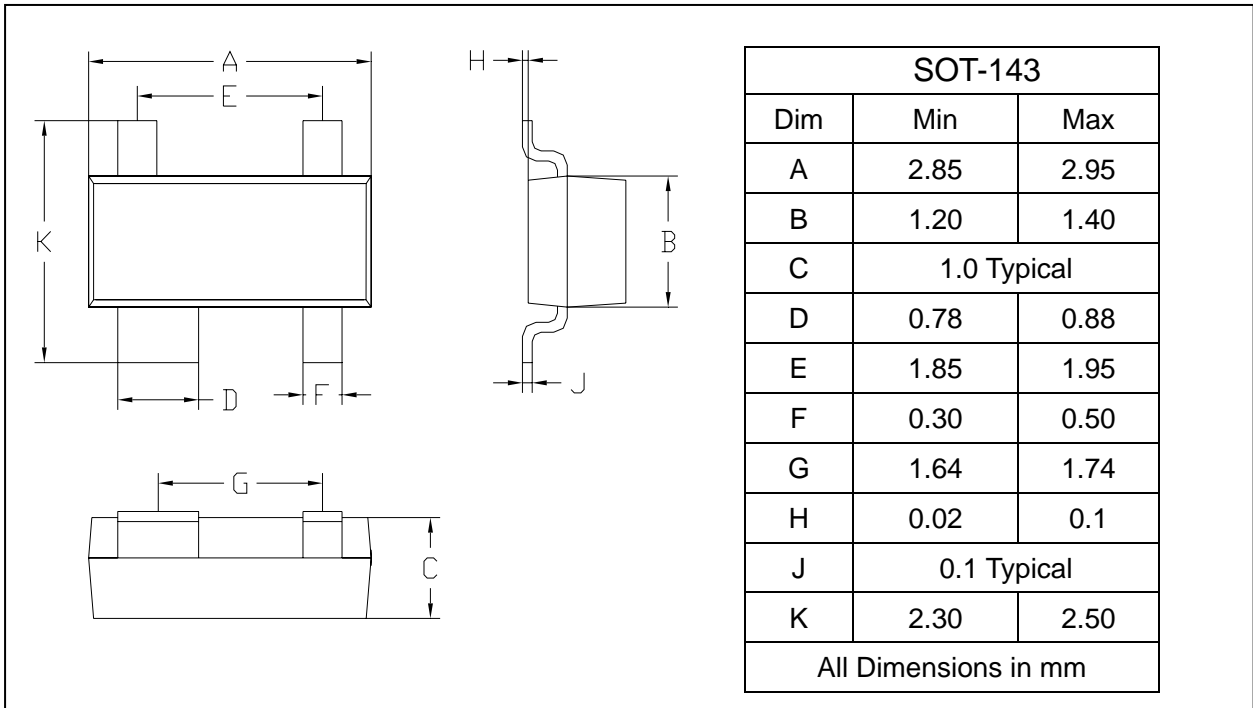
$f = 1\text{ MHz}$ ;  $T_j = 25\text{ }^\circ\text{C}$ .

Fig.6 Diode capacitance as a function of reverse voltage; typical values.

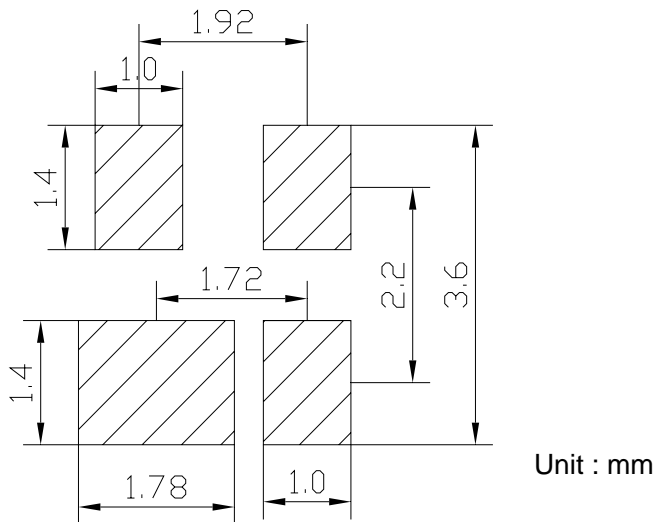
## PACKAGE OUTLINE

Plastic surface mounted package

SOT-143



## SOLDERING FOOTPRINT



## PACKAGE INFORMATION

Device	Package	Shipping
BAS56	SOT-143	2000/Tape&Reel